

1-Line High Power TVS Diode

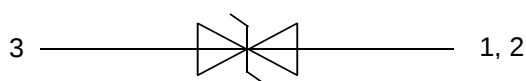
Description

The PESDU4521P4-3 is a high power TVS, utilizing to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The PESDU4521P4-3 complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

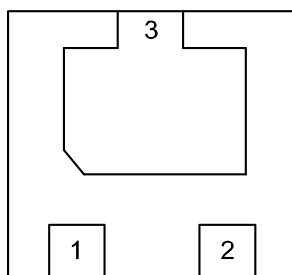
Features

- 6000W peak pulse power (8/20 μs)
- Operating voltage: 4.5V
- Ultra low clamping voltage
- One power line protects
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 260A (8/20 μs)
- RoHS Compliant

Dimensions and Pinonfiguration



Circuit Diagram 1, 2



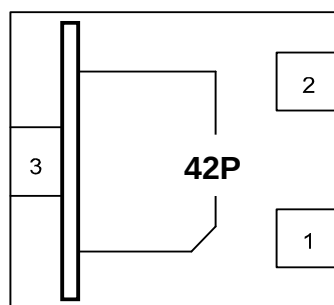
Mechanical Characteristics

- Package: DFN2020-3
- Lead Finish: NiPdAu
- Case Material: "Green" Molding Compound
- Moisture Sensitivity: Level 3 per J-STD-020
- Marking Information: See Below

Applications

- Power Management
- Industrial Application
- Power Supply Protection

Marking Information



42P = Device Making Code

Bar denotes Cathode

Ordering Information

Part Number	Shipping	Reel Size
PESDU4521P4-3	3000/Tape & Reel	7 inch

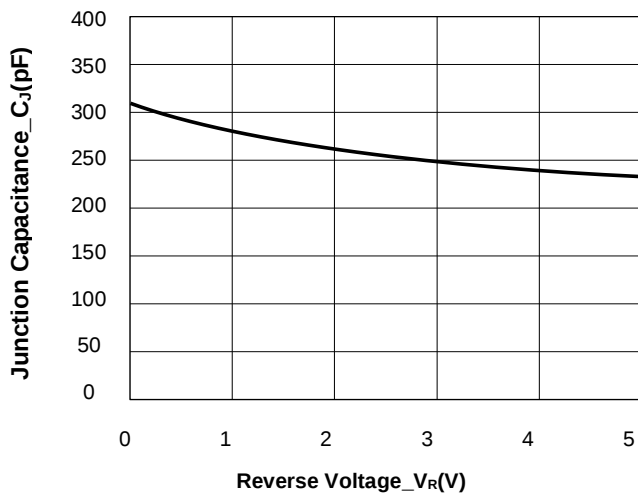
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P _{PK}	4700	W
Peak Pulse Current (8/20μs)	I _{PP}	260	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	kV
Operating Temperature Range	T _{OP}	-55 to +125	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

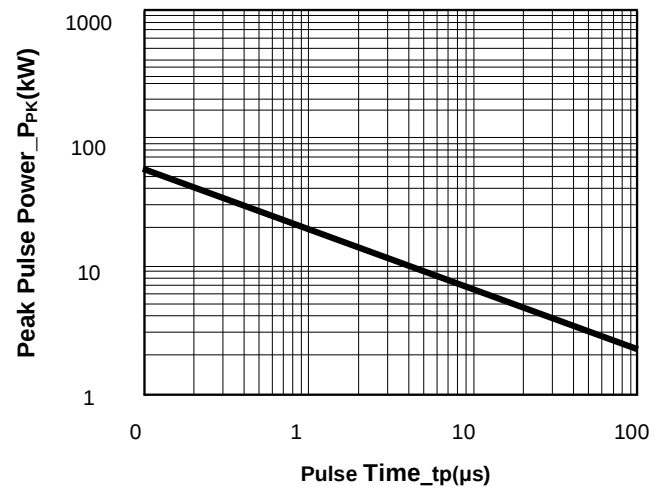
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			4.5	V	
Breakdown Voltage	V _{BR}	4.8			V	I _T = 1mA
Reverse Leakage Current	I _R			1	μA	V _{RWM} = 4.5V
Clamping Voltage	V _C			8.5	V	I _{PP} = 50A (8/20μs pulse)
Clamping Voltage	V _C			18	V	I _{PP} = 260A (8/20μs pulse)
Junction Capacitance	C _J		300		pF	V _R = 0V, f = 1MHz

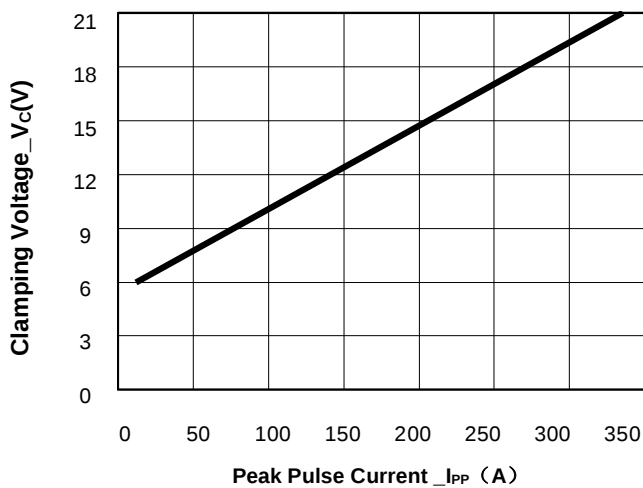
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



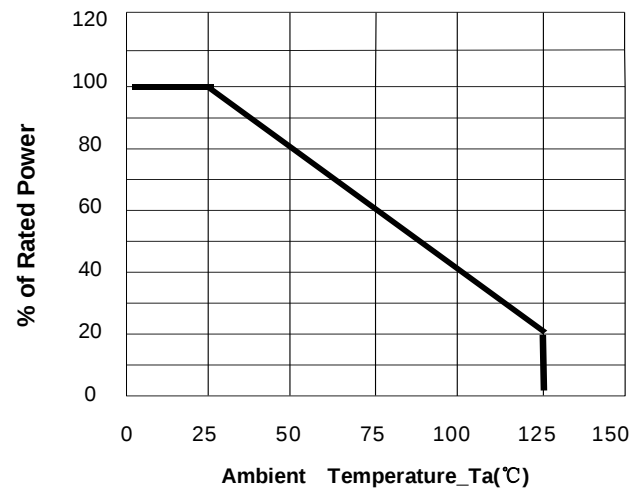
Junction Capacitance vs. Reverse Voltage



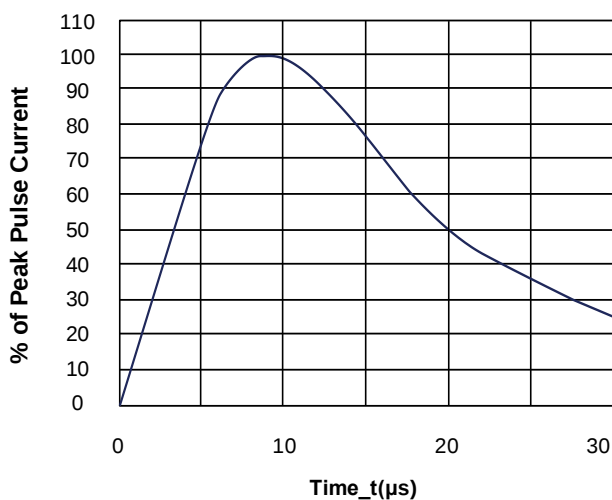
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

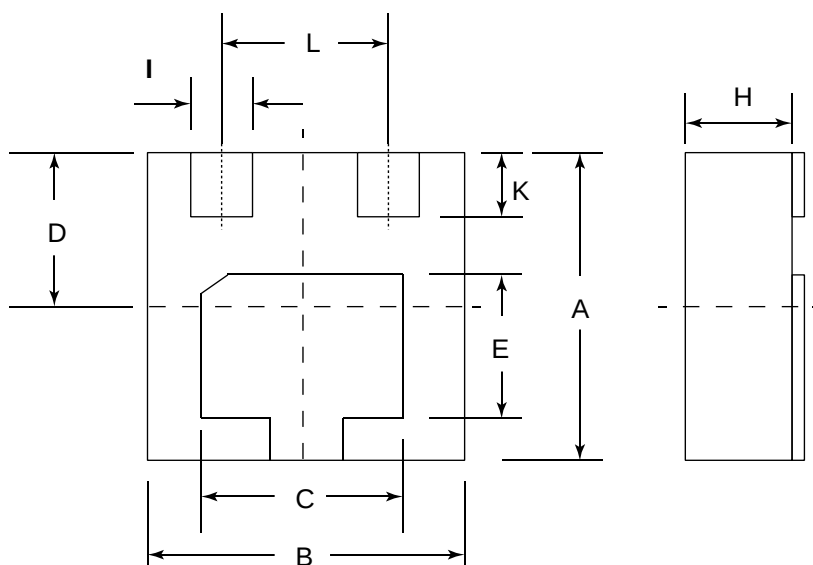


Power Derating Curve



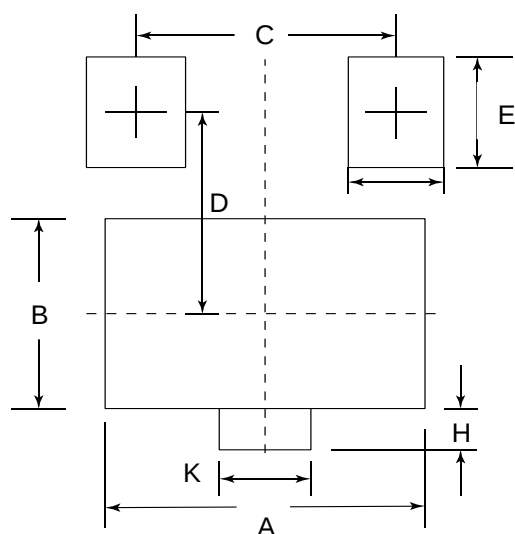
8/20 μs Pulse Waveform

DFN2020-3 Package Outline Drawing



DIM	Millimeters		
	Min	Nom	Max
A	1.90	2.00	2.10
B	1.90	2.00	2.10
C	1.40	1.50	1.60
D	0.95	1.0	1.05
E	0.90	1.00	1.10
H			0.65
L		1.3	
I	0.25	0.30	0.35
K	0.35	0.40	0.45

Suggested Land Pattern



SYM	MILLIMETERS
A	1.60
B	1.10
C	1.30
D	1.05
E	0.50
K	0.40
H	0.25